

ANN-8801 REV A.

THERMAL POWER TESTING METHODOLOGY FOR CHIP, FLANGE, AND PCB-MOUNTED RESISTORS

In the global electronics market, resistors are used in a variety of applications and deployed to handle a many different duties ranging from dissipating excess power, to providing a system safety mechanism, to providing a matching device, among other tasks.

A resistor operates by converting electrical energy into heat energy by means of a resistive element. In most applications, resistors are mounted to a heatsink, a flange (as depicted in Figure 1 and Figure 2), or directly on a PCB using industry-standard solders. When DC or RF power is input into the resistor, the power is converted by the resistive element into heat. In the case of a flange-mounted component, heat flows from the element into the ceramic dielectric material and the solder joint, through the flange and into the heatsink.

Typically, there are two main design considerations for validating a resistor chip design:

- **Temperatures/heat generated in the application and the effect this heat has on the resistor's materials:** High temperatures may exceed the limitations of the materials used in a resistor (causing reliability issues). Moreover, excessive temperatures sustained for a duration of time can even result in permanent damage or complete failure of the resistor.
- **Coefficient of Thermal Expansion (CTE) mismatches between the resistor's materials:** When power is dissipated in a resistive component, a temperature gradient through the ceramic, solder, flange (or PCB), heatsink results. The temperature gradient, along with the CTE mismatch of the materials, creates stress. The solder joint (Figure 2) is subject to fatigue cracking due to repeated exposure to this stress. A robust design is required to ensure that, as the resistor is cycled on and off over time, its materials will not fatigue and degrade and eventually lead to failure.

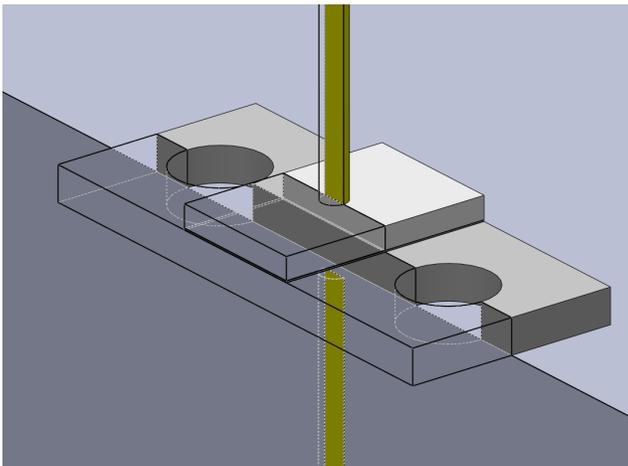


FIGURE 1: CROSS-SECTIONAL VIEW OF TEST SETUP

The materials used in Anaren resistive components are selected to minimize the Coefficient of Thermal Expansion (CTE) mismatch and reduce stress. To accomplish this, Anaren has developed a test method that ensures that the design is robust, meets the desired power handling requirements, and performs consistently and reliably for the design life of the resistive component. More specifically, a customized test station is utilized to determine and validate a resistor's power handling capabilities and design. This test station has the ability to finely control the interface temperature (see Figure 2) during testing, allowing for accurate, reliable test data and analysis.

As seen in Figure 1 and Figure 2, the resistive component is soldered to a flange and then mounted to the test station's heat sink. Thermocouples are used to monitor and collect temperature data during the testing. The Film Thermocouple monitors the resistive elements temperature. The Interface Thermocouple is embedded in the heatsink (located just beneath the flange-heatsink interface) and monitors the interface temperature.

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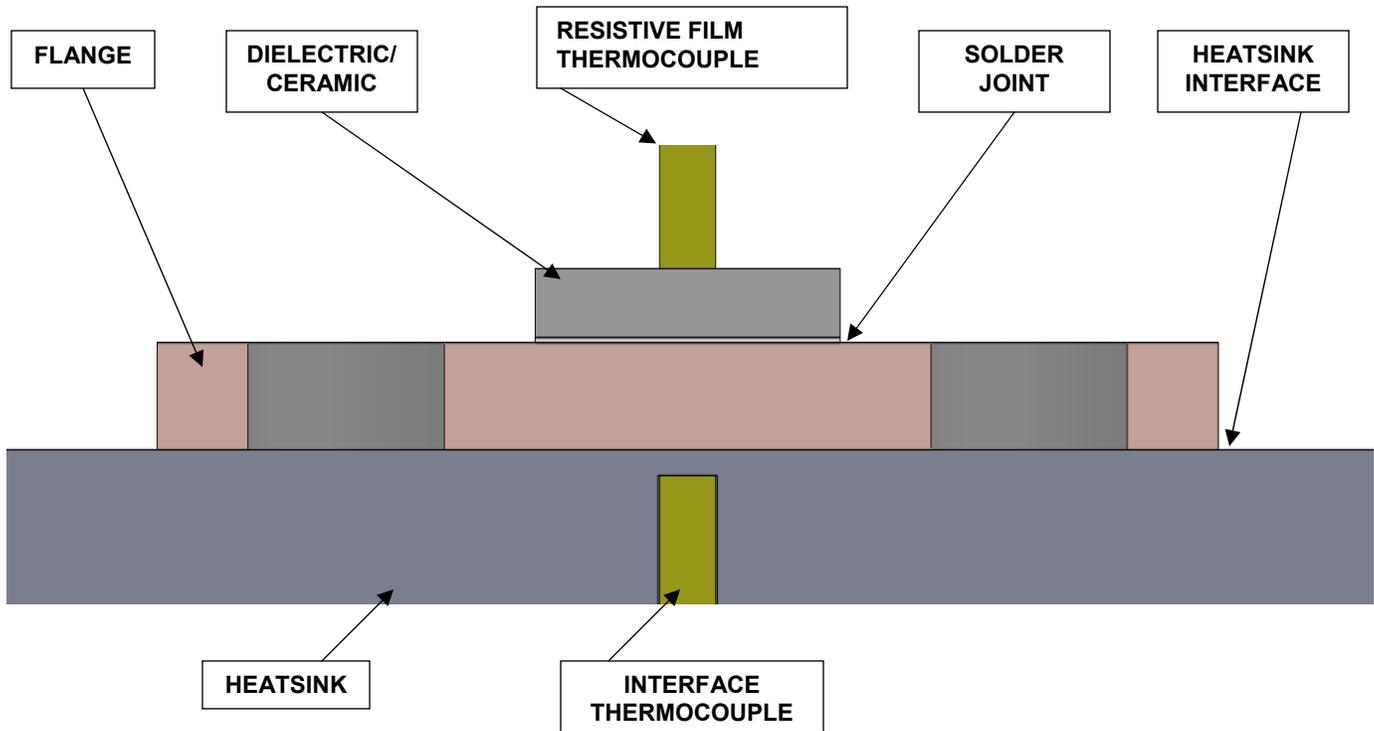


FIGURE 2: CROSS-SECTIONAL SIDE VIEW OF TEST SETUP

Testing is performed in two (2) phases. Phase 1 verifies that the resistive component design will handle the intended maximum input power. This phase of testing subjects the resistive component to the intended maximum input power while maintaining a 100C interface temperature (refer to Figure 3 – “Test Point”). The resistive film temperature is monitored to verify that maximum operating temperature boundary limits are not exceeded. If the resistive component stays within the set temperature boundary range, and if there is no damage to the resistive element, the chip is subjected to the second phase of testing.

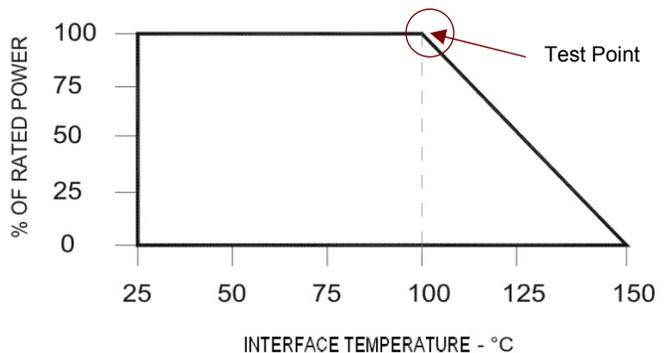


FIGURE 3: TYPICAL DERATING CURVE FOR INPUT POWER

Once the chip’s power handling capability is verified by the first phase of the testing, it is subjected to the second phase of testing designed to verify the long term reliability. Phase 2 testing subjects the resistive component to cyclic thermal/power levels to verify that

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the unit can survive the stress resulting from CTE mismatches; a typical profile for the test method is shown in Figure 4. The resistive element/film temperature is monitored during the test. At the conclusion of the test the entire resistor is analyzed to ensure it was not damaged. On the start of a cycle, the system and the device under test (DUT – in this case, the resistor soldered to the flange) is at room temperature (25°C). Full input power is applied to the chip and the interface temperature (or “Flange Temperature” as depicted in Figure 4) is brought to and maintained at 100°C. Once the flange/interface temperature stabilizes (at 100°C), the chip is pulsed 10 cycles of ‘power on – power off’; essentially, the pulsing consists of full power applied for 3 seconds preceded by no power for 3 seconds. At the completion of 10 cycles, power to the chip is turned off and the entire system (heatsink and DUT) is cooled back down to room temperature. This process is repeated 300 times.

Once testing is complete, a post examination of the chip is performed to ensure that there is no permanent damage or change due to testing: a permanent change in resistance indicates that the chip is at risk for unreliable performance over the design life. Additionally, this two phase testing process is completed on multiple samples to ensure confidence in the data accuracy and ultimately the reliability of the resistor.

For more information on this application note or other aspects of resistors, contact Anaren:

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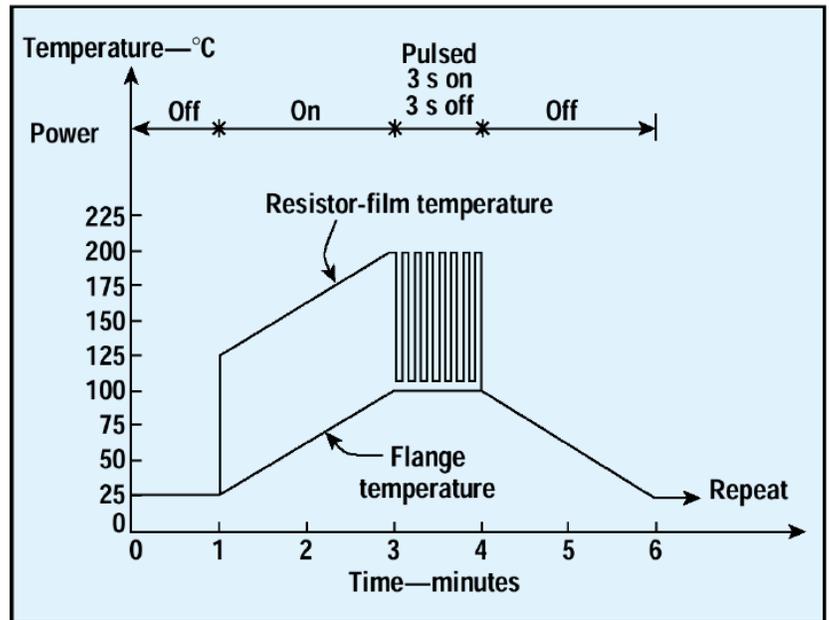


FIGURE 4: PHASE TWO TEST PROFILE FOR CTE MISMATCH